

# KB DELPS2.12

## TOPLED® E1608

The TOPLED E1608 expands OSRAM Opto Semiconductors' low power portfolio by offering one of the smallest LED Industry standard footprints in a highly reliable and well proved package concept.

Its outstanding performance is suitable for a huge variety of applications especially automotive interior where a small package design with excellent reliability is needed. The TOPLED E1608 is available in different colors and brightness levels.



## Applications

- Cluster, Button Backlighting
- Electronic Equipment
- Interior Illumination (e.g. Ambient Map)

## Features:

- Package: white SMT package, colorless clear resin
- Chip technology: InGaN on Sapphire
- Typ. Radiation: 120° (Lambertian emitter)
- Color:  $\lambda_{\text{dom}} = 466 \text{ nm}$  (● blue)
- Corrosion Robustness Class: 2B
- Qualifications: AEC-Q102 Qualified
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

## Ordering Information

Type	Luminous Intensity <sup>1)</sup> $I_F = 10 \text{ mA}$ $I_v$	Ordering Code
KB DELPS2.12-QHRI-24-Z555	82 ... 180 mcd	Q65112A6350

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## Maximum Ratings

Parameter	Symbol		Values
Operating Temperature	$T_{op}$	min.	-40 °C
		max.	110 °C
Storage Temperature	$T_{stg}$	min.	-40 °C
		max.	110 °C
Junction Temperature	$T_j$	max.	125 °C
Forward current $T_s = 25\text{ °C}$	$I_F$	min.	1 mA
		max.	20 mA
Surge Current $t \leq 10\ \mu\text{s}$ ; $D = 0.005$ ; $T_s = 25\text{ °C}$	$I_{FS}$	max.	40 mA
Reverse voltage <sup>2)</sup> $T_s = 25\text{ °C}$	$V_R$	max.	5 V
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	$V_{ESD}$		2 kV

## Characteristics

$I_F = 10 \text{ mA}$ ;  $T_S = 25 \text{ °C}$

Parameter	Symbol		Values
Peak Wavelength	$\lambda_{\text{peak}}$	typ.	461 nm
Dominant Wavelength <sup>3)</sup> $I_F = 10 \text{ mA}$	$\lambda_{\text{dom}}$	min.	460 nm
		typ.	466 nm
		max.	472 nm
Viewing angle at 50% $I_V$	$2\varphi$	typ.	120 °
Forward Voltage <sup>4)</sup> $I_F = 10 \text{ mA}$	$V_F$	min.	2.70 V
		typ.	2.80 V
		max.	3.20 V
Reverse current <sup>2)</sup> $V_R = 5 \text{ V}$	$I_R$	typ.	0.01 $\mu\text{A}$
		max.	10 $\mu\text{A}$
Real thermal resistance junction/ambient <sup>5)6)</sup>	$R_{\text{thJA real}}$	max.	570 K / W
Real thermal resistance junction/solderpoint <sup>5)</sup>	$R_{\text{thJS real}}$	typ.	120 K / W
		max.	210 K / W

## Brightness Groups

Group	Luminous Intensity <sup>1)</sup> $I_F = 10 \text{ mA}$ min. $I_v$	Luminous Intensity <sup>1)</sup> $I_F = 10 \text{ mA}$ max. $I_v$	Luminous Flux <sup>7)</sup> $I_F = 10 \text{ mA}$ typ. $\Phi_v$
QH	82 mcd	97 mcd	270 mlm
QI	97 mcd	112 mcd	310 mlm
RG	112 mcd	130 mcd	360 mlm
RH	130 mcd	150 mcd	420 mlm
RI	150 mcd	180 mcd	500 mlm

## Forward Voltage Groups

Group	Forward Voltage <sup>4)</sup> $I_F = 10 \text{ mA}$ min. $V_F$	Forward Voltage <sup>4)</sup> $I_F = 10 \text{ mA}$ max. $V_F$
Z5	2.70 V	2.95 V
55	2.95 V	3.20 V

## Wavelength Groups

Group	Dominant Wavelength <sup>3)</sup> $I_F = 10 \text{ mA}$ min. $\lambda_{\text{dom}}$	Dominant Wavelength <sup>3)</sup> $I_F = 10 \text{ mA}$ max. $\lambda_{\text{dom}}$
2	460 nm	464 nm
3	464 nm	468 nm
4	468 nm	472 nm

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## Group Name on Label

**Example: QH-2-55**

Brightness

Wavelength

Forward Voltage

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QH

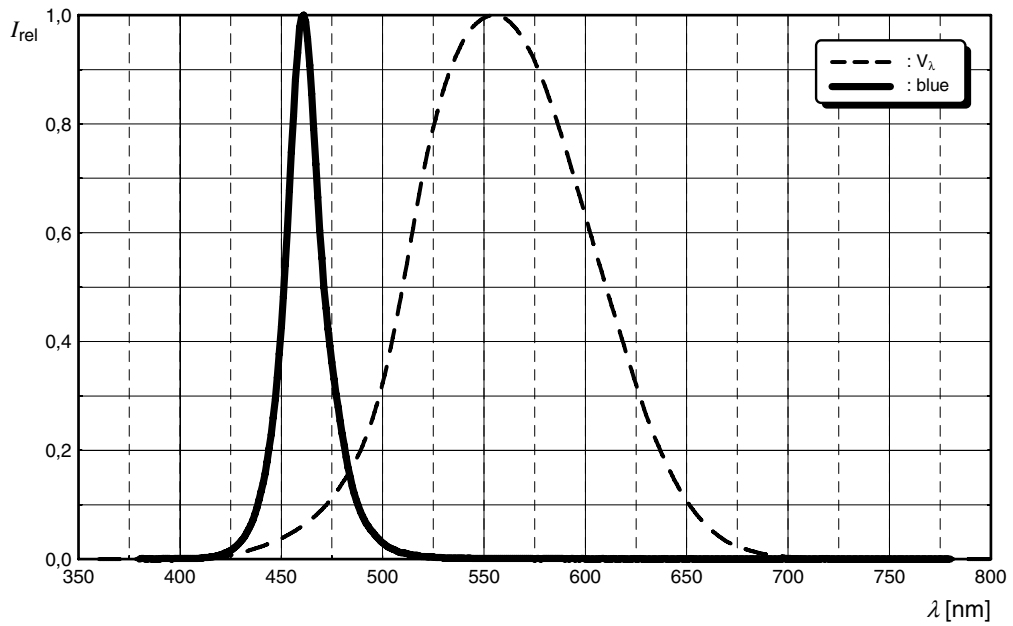
2

55

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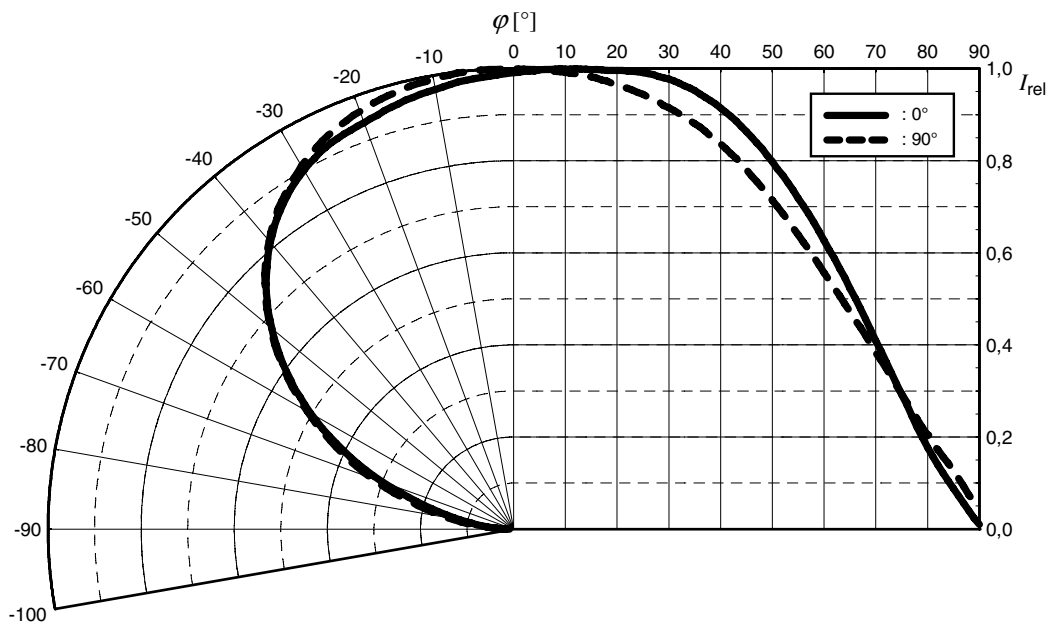
### Relative Spectral Emission <sup>7)</sup>

$I_{rel} = f(\lambda); I_F = 10 \text{ mA}; T_S = 25 \text{ }^\circ\text{C}$



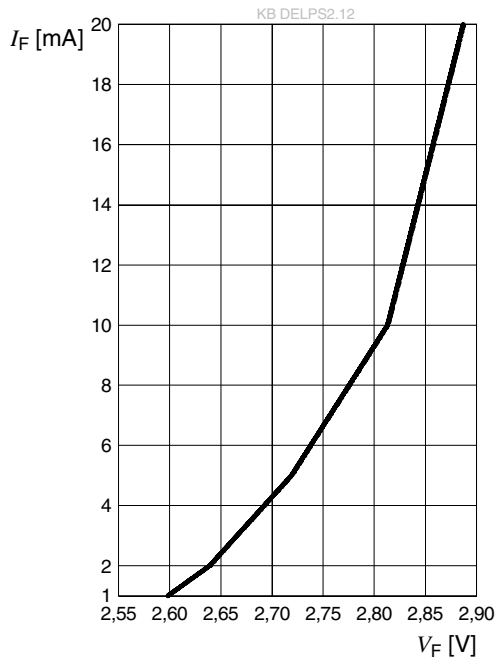
### Radiation Characteristics <sup>7)</sup>

$I_{rel} = f(\phi); T_S = 25 \text{ }^\circ\text{C}$



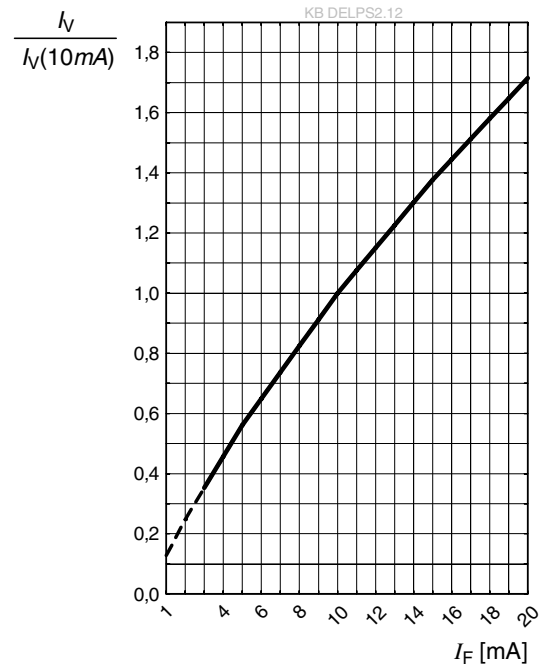
### Forward current <sup>7)</sup>

$$I_F = f(V_F); T_S = 25 \text{ }^\circ\text{C}$$



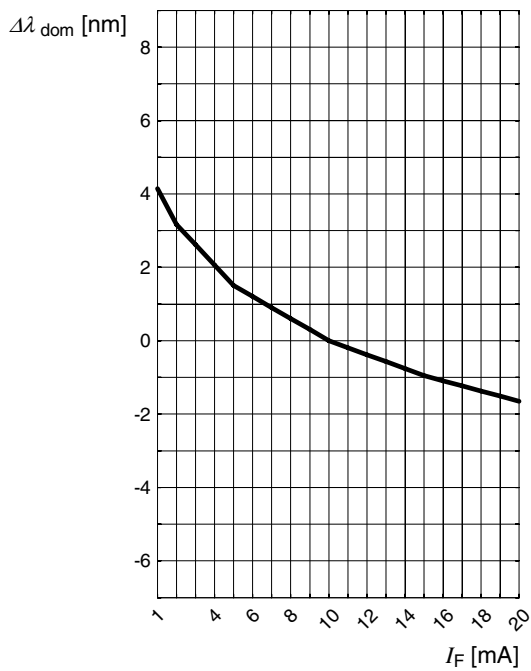
### Relative Luminous Intensity <sup>7), 8)</sup>

$$I_V/I_V(10 \text{ mA}) = f(I_F); T_S = 25 \text{ }^\circ\text{C}$$



### Dominant Wavelength <sup>7)</sup>

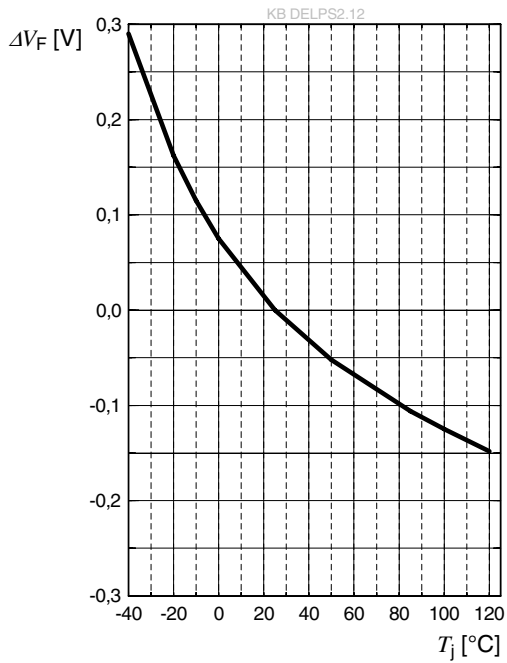
$$\lambda_{\text{dom}} = f(I_F); T_S = 25 \text{ }^\circ\text{C}$$





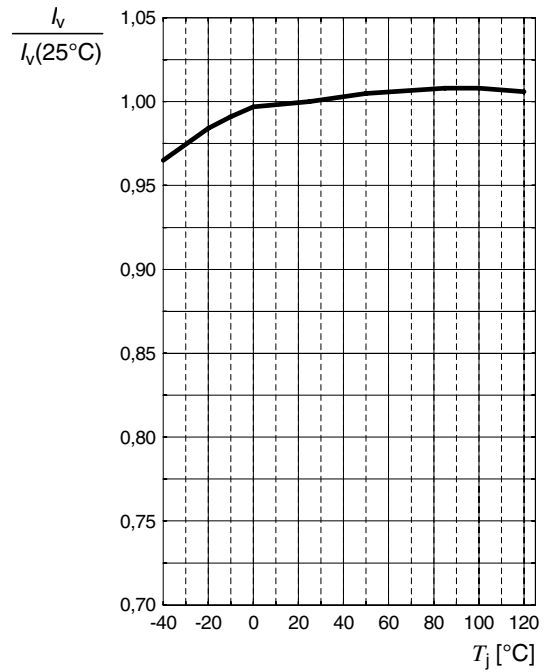
### Forward Voltage <sup>7)</sup>

$$\Delta V_F = V_F - V_F(25\text{ °C}) = f(T_j); I_F = 10\text{ mA}$$



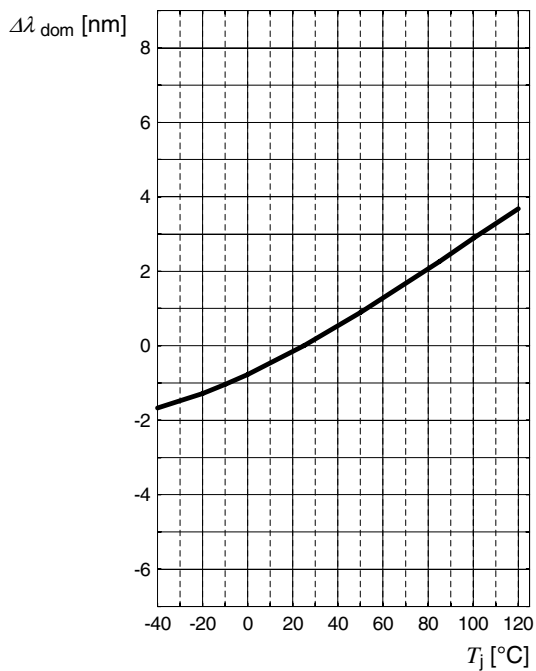
### Relative Luminous Intensity <sup>7)</sup>

$$I_V/I_V(25\text{ °C}) = f(T_j); I_F = 10\text{ mA}$$



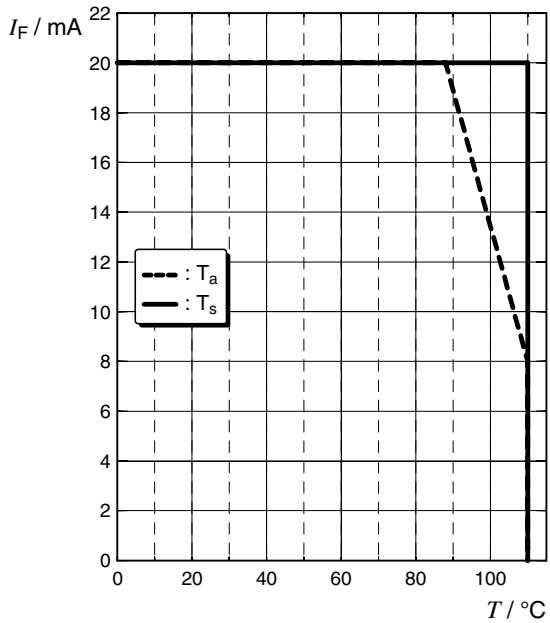
### Dominant Wavelength <sup>7)</sup>

$$\lambda_{\text{dom}} = f(T_j); I_F = 10\text{ mA}$$



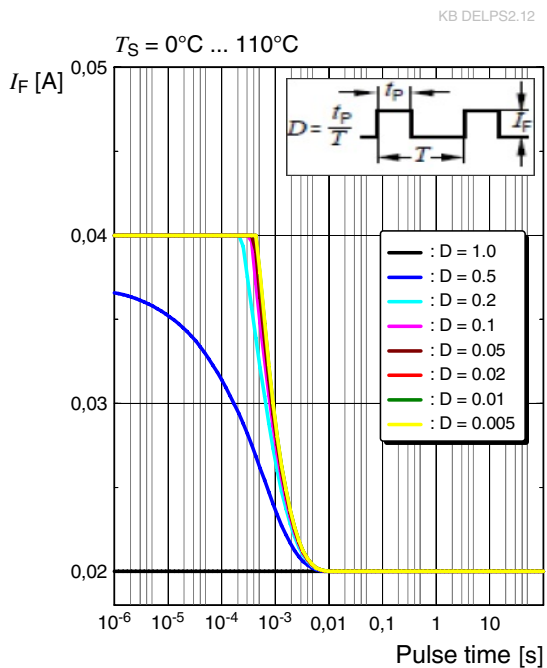
## Max. Permissible Forward Current

$$I_F = f(T)$$

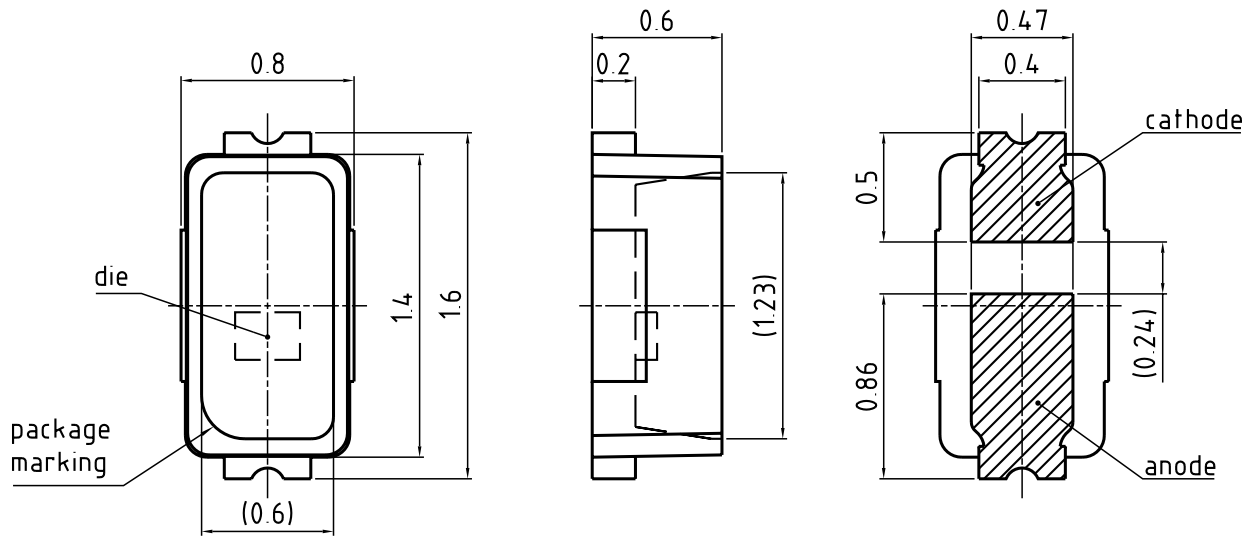



## Permissible Pulse Handling Capability

$$I_F = f(t_p); D: \text{Duty cycle}$$



**Dimensional Drawing** <sup>9)</sup>



general tolerance  $\pm 0.1$   
 lead finish Ag 

C63062-A4275-A1.-02

**Further Information:**

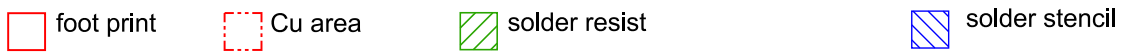
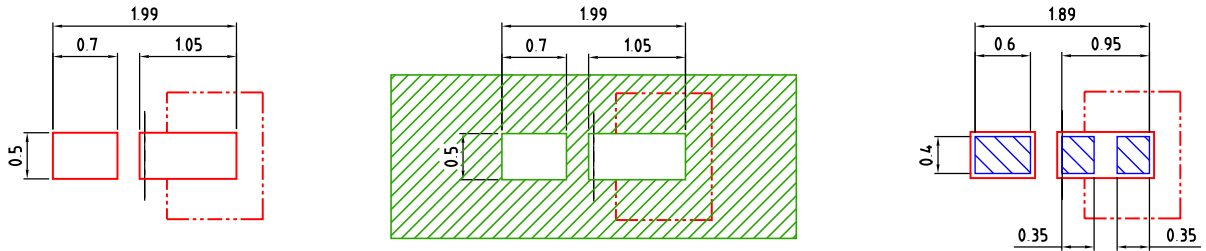
**Approximate Weight:** 2.0 mg

**Package marking:** Anode

**Corrosion test:** Class: 2B

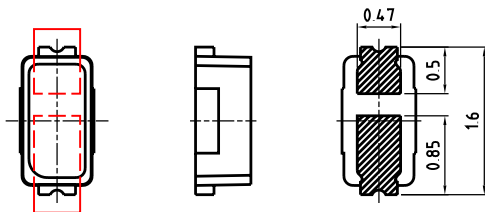
Test condition: 25°C / 75 % RH / 10 ppm H<sub>2</sub>S / 21 days (IEC 60068-2-43)

## Recommended Solder Pad <sup>9)</sup>



The usage of solder resist between anode and cathode pads is mandatory for applications where water may condense

### Component Location on Pad



E062.3010.187 -02

All products are packed in a dry pack bag (Moisture Barrier Bag, MBB) according MIL-PRF-81705, after opening the MBB the products should go to reflow soldering process. Unused remaining LEDs should be protected from environment due to silver plated soldering terminal. In order to maintain solderability it is recommended to protect the silver plated solder terminals from corrosive environment before soldering. For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere.

## Reflow Soldering Profile

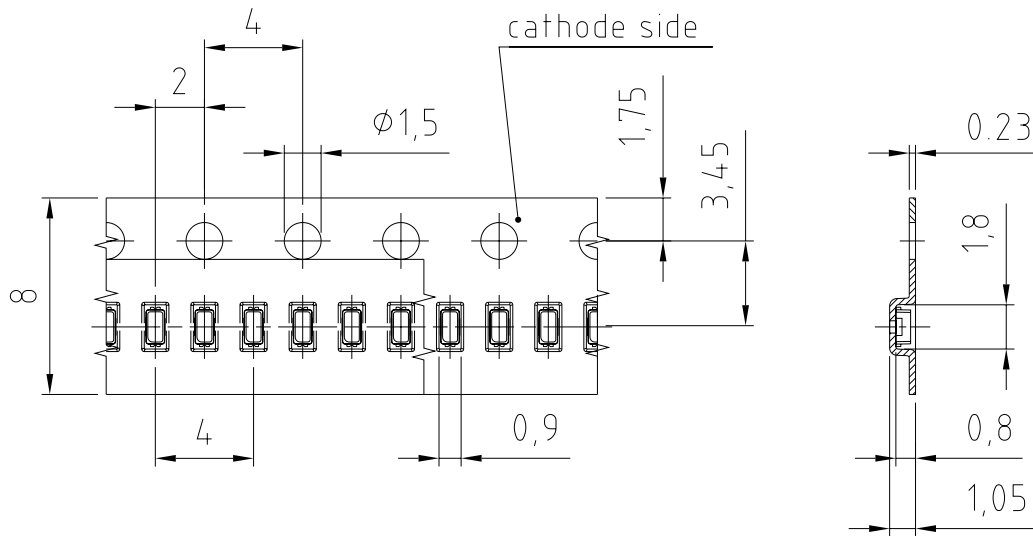
Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat <sup>*)</sup> 25 °C to 150 °C			2	3	K/s
Time $t_s$ $T_{Smin}$ to $T_{Smax}$	$t_s$	60	100	120	s
Ramp-up rate to peak <sup>*)</sup> $T_{Smax}$ to $T_p$			2	3	K/s
Liquidus temperature	$T_L$		217		°C
Time above liquidus temperature	$t_L$		80	100	s
Peak temperature	$T_p$		245	260	°C
Time within 5 °C of the specified peak temperature $T_p - 5$ K	$t_p$	10	20	30	s
Ramp-down rate* $T_p$ to 100 °C			3	6	K/s
Time 25 °C to $T_p$				480	s

All temperatures refer to the center of the package, measured on the top of the component  
 \*) slope calculation  $DT/Dt$ :  $Dt$  max. 5 s; fulfillment for the whole T-range

**Taping** <sup>9)</sup>



C63062-A4275-B5 -02

**Tape and Reel** <sup>10)</sup>



**Reel Dimensions**

A	W	$N_{\min}$	$W_1$	$W_{2\max}$	Pieces per PU
180 mm	$8 + 0.3 / - 0.1$ mm	60 mm	$8.4 + 2$ mm	14.4 mm	5000

### Barcode-Product-Label (BPL)

**OSRAM Opto Semiconductors**      LX XXXX      BIN1: XX-XX-X-XXX-X

RoHS Compliant

(6P) BATCH NO: 1234567890      ML Temp    ST  
X    XXX °C X

(1T) LOT NO: 1234567890      (9D) D/C: 1234      Pack: RXX  
DEMY    XXX  
X\_X123\_1234.1234 X

(X) PROD NO: 123456789(Q)QTY: 9999      (G) GROUP: XX-XX-X-X

The diagram shows a rectangular label with rounded corners. It contains the OSRAM logo and product name at the top left. To the right are fields for 'LX XXXX' and 'BIN1: XX-XX-X-XXX-X'. Below the logo is a 'RoHS Compliant' statement. The label features three main barcode sections: a top one for '(6P) BATCH NO: 1234567890', a middle one for '(1T) LOT NO: 1234567890' and '(9D) D/C: 1234', and a bottom one for '(X) PROD NO: 123456789(Q)QTY: 9999' and '(G) GROUP: XX-XX-X-X'. To the right of the middle barcode is a 'No Moisture' symbol (a circle with a diagonal line and three drops) and 'ML Temp ST X XXX °C X'. Below that is 'Pack: RXX', 'DEMY XXX', and 'X\_X123\_1234.1234 X'. A QR code is located on the right side of the label.

OHA04563

### Dry Packing Process and Materials <sup>9)</sup>

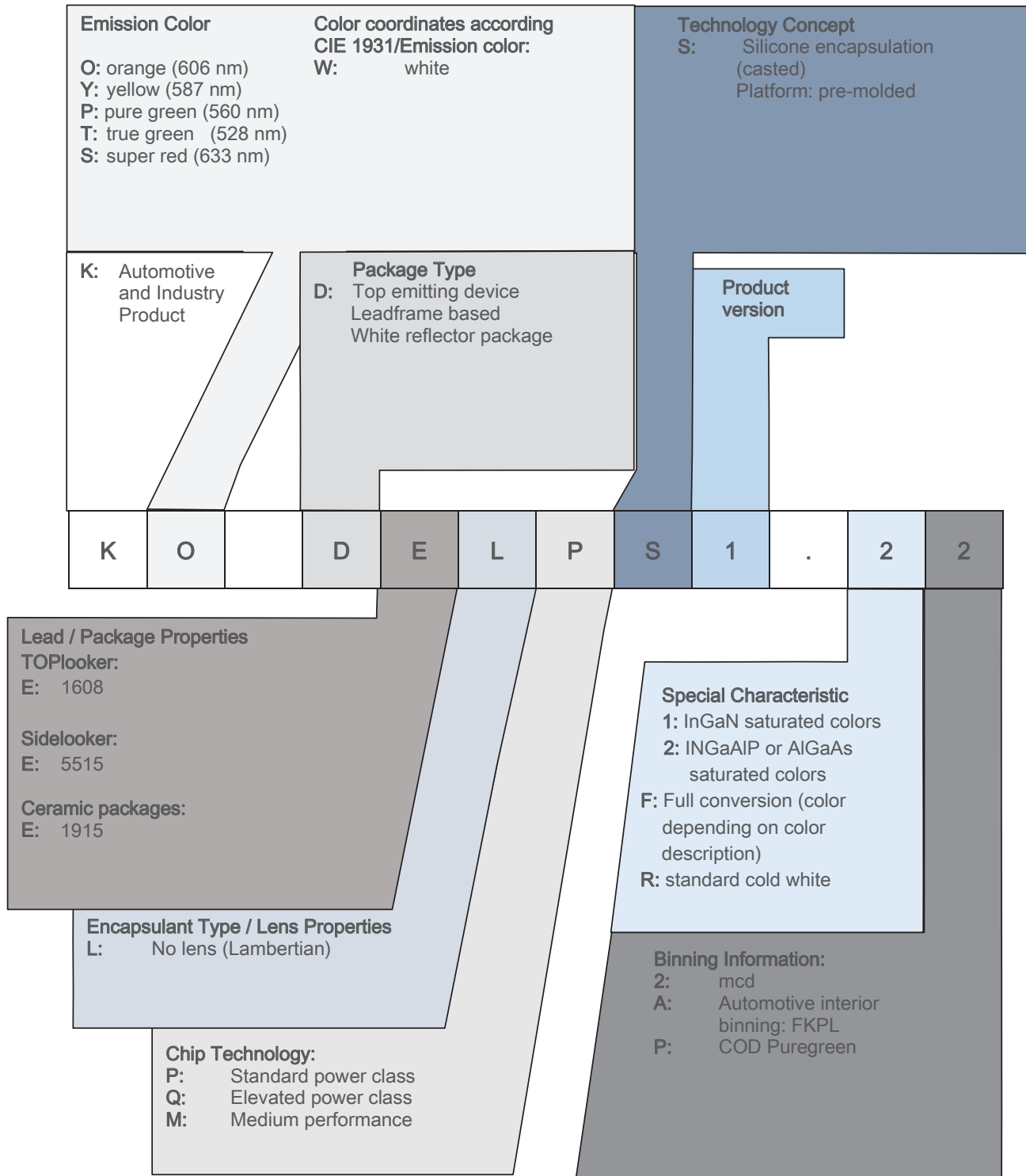


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Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



## Type Designation System



## Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit [www.osram-os.com/appnotes](http://www.osram-os.com/appnotes)

## Disclaimer

### **Attention please!**

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

### **Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

### **Product and functional safety devices/applications or medical devices/applications**

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.

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## Glossary

- 1) **Brightness:** Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of  $\pm 8\%$  and an expanded uncertainty of  $\pm 11\%$  (acc. to GUM with a coverage factor of  $k = 3$ ).
- 2) **Reverse Operation:** This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- 3) **Wavelength:** The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of  $\pm 0.5$  nm and an expanded uncertainty of  $\pm 1$  nm (acc. to GUM with a coverage factor of  $k = 3$ ).
- 4) **Forward Voltage:** The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of  $\pm 0.05$  V and an expanded uncertainty of  $\pm 0.1$  V (acc. to GUM with a coverage factor of  $k = 3$ ).
- 5) **Thermal Resistance:**  $R_{th\ max}$  is based on statistic values ( $6\sigma$ ).
- 6) **Thermal Resistance:**  $R_{thJA}$  results from mounting on PC board FR 4 (pad size 16 mm<sup>2</sup> per pad)
- 7) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 8) **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- 9) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with  $\pm 0.1$  and dimensions are specified in mm.
- 10) **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

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## Revision History

Version	Date	Change
1.2	2018-12-04	Additional Information
1.3	2019-10-22	Ordering Information
1.4	2020-03-05	Derating (Diagrams)
1.5	2020-03-09	Schematic Transportation Box Dimensions of Transportation Box
1.6	2020-06-04	Further Information

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